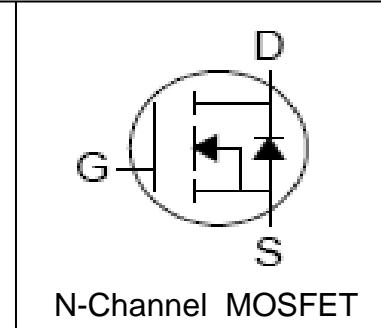
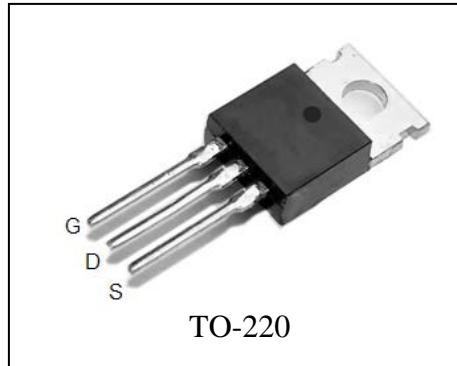


Features

- 70V/120A,
 $R_{DS(ON)} = 6\text{m}\Omega$ (Typ.) @ $V_{GS} = 10\text{V}$
- Ultra Low On-Resistance
- Exceptional dv/dt capability
- Fast Switching and Fully Avalanche Rated
- 100% avalanche tested
- 175°C Operating Temperature
- Lead Free and Green Available

Applications

- Switching Application Systems
- Inverter Systems
- DC Motor Controller

Pin Description**Absolute Maximum Ratings**

Symbol	Parameter	Rating	Unit
Common Ratings ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)			
V_{DSS}	Drain-Source Voltage	70	V
V_{GSS}	Gate-Source Voltage	± 25	
T_J	Maximum Junction Temperature	175	°C
T_{STG}	Storage Temperature Range	-55 to 175	°C
I_S	Diode Continuous Forward Current	$T_C = 25^\circ\text{C}$	A
		120 ⁽¹⁾	
Mounted on Large Heat Sink			
I_{DP}	300μs Pulse Drain Current Tested	$T_C = 25^\circ\text{C}$	A
		380 ⁽²⁾	
I_D	Continuous Drain Current	$T_C = 25^\circ\text{C}$	A
		$T_C = 100^\circ\text{C}$	
P_D	Maximum Power Dissipation	$T_C = 25^\circ\text{C}$	W
		$T_C = 100^\circ\text{C}$	
$R_{θJC}$	Thermal Resistance-Junction to Case	1	°C/W
Drain-Source Avalanche Ratings			
$E_{AS}^{(3)}$	Avalanche Energy, Single Pulsed	424	mJ

Electrical Characteristics ($T_A=25^\circ\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Test Condition	IRF3205Z			Unit
			Min.	Typ.	Max.	
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}$, $I_{\text{DS}}=250\mu\text{A}$	70			V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{\text{DS}}=60\text{V}$, $V_{\text{GS}}=0\text{V}$ $T_J=85^\circ\text{C}$			1	μA
					30	
$V_{\text{GS(th)}}$	Gate Threshold Voltage	$V_{\text{DS}}=V_{\text{GS}}$, $I_{\text{DS}}=250\mu\text{A}$	2	3	4	V
I_{GSS}	Gate Leakage Current	$V_{\text{GS}}=\pm 20\text{V}$, $V_{\text{DS}}=0\text{V}$			± 100	nA
$R_{\text{DS(ON)}}$ ^④	Drain-Source On-state Resistance	$V_{\text{GS}}=10\text{V}$, $I_{\text{DS}}=40\text{A}$		6	7.6	$\text{m}\Omega$
Diode Characteristics						
V_{SD} ^④	Diode Forward Voltage	$I_{\text{SD}}=40\text{A}$, $V_{\text{GS}}=0\text{V}$			1.2	V
t_{rr}	Reverse Recovery Time	$I_{\text{SD}}=40\text{A}$, $dI_{\text{SD}}/dt=100\text{A}/\mu\text{s}$		50		ns
Q_{rr}	Reverse Recovery Charge			95		nC
Dynamic Characteristics ^⑤						
R_{G}	Gate Resistance	$V_{\text{GS}}=0\text{V}$, $V_{\text{DS}}=0\text{V}$, $F=1\text{MHz}$		1.3		Ω
C_{iss}	Input Capacitance	$V_{\text{GS}}=0\text{V}$, $V_{\text{DS}}=30\text{V}$, Frequency=1.0MHz		4500		pF
C_{oss}	Output Capacitance			430		
C_{rss}	Reverse Transfer Capacitance			240		
$t_{\text{d(ON)}}$	Turn-on Delay Time	$V_{\text{DD}}=30\text{V}$, $R_{\text{L}}=30\Omega$, $I_{\text{DS}}=1\text{A}$, $V_{\text{GEN}}=10\text{V}$, $R_{\text{G}}=8\Omega$		14		ns
t_{r}	Turn-on Rise Time			17		
$t_{\text{d(OFF)}}$	Turn-off Delay Time			40		
t_{f}	Turn-off Fall Time			62		
Gate Charge Characteristics ^⑤						
Q_{g}	Total Gate Charge	$V_{\text{DS}}=30\text{V}$, $V_{\text{GS}}=10\text{V}$, $I_{\text{DS}}=40\text{A}$		78		nC
Q_{gs}	Gate-Source Charge			13		
Q_{gd}	Gate-Drain Charge			24		

Notes: ①Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 75A.

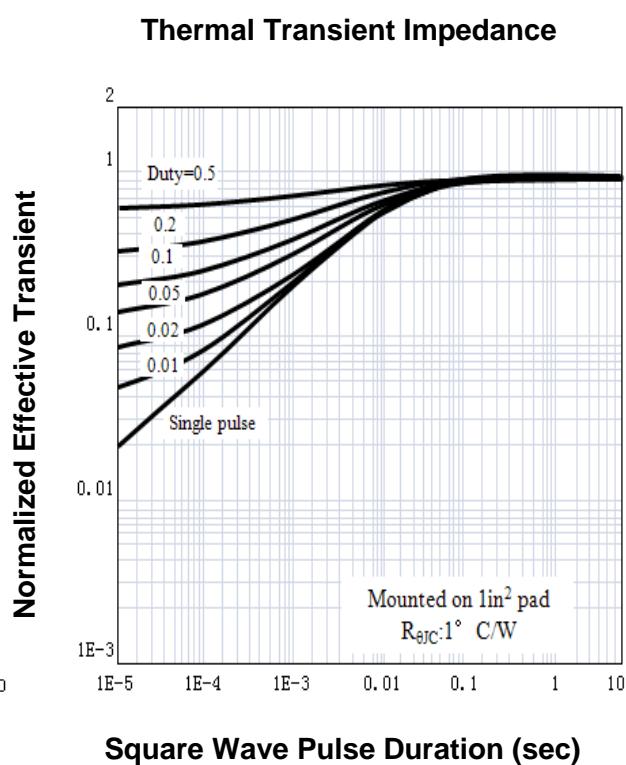
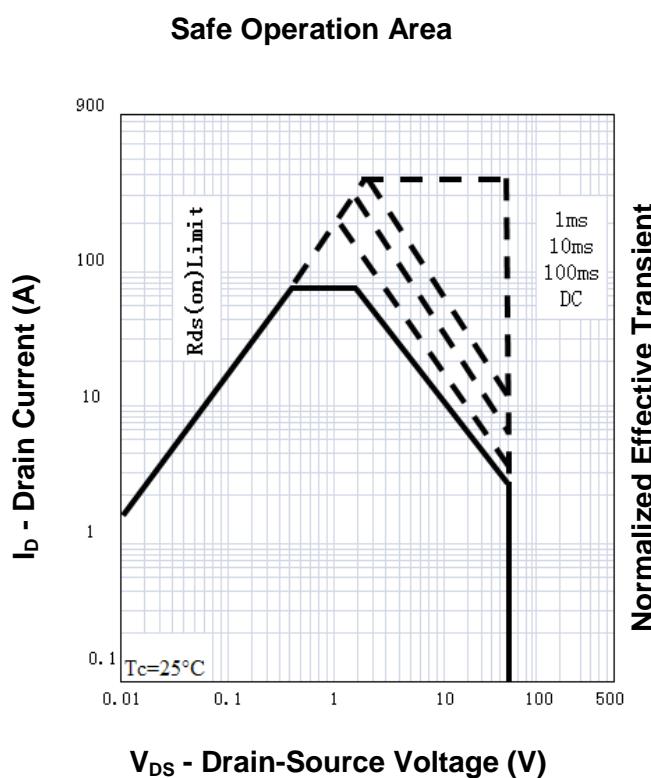
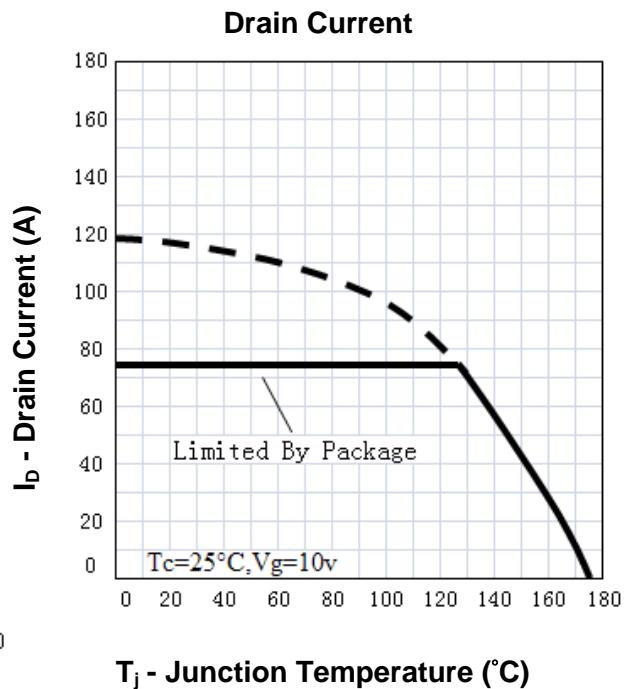
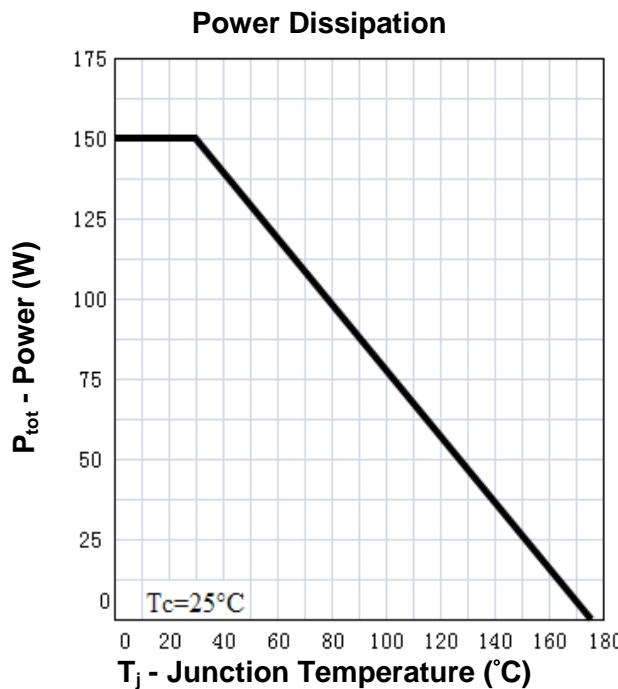
②Pulse width limited by safe operating area.

③Limited by $T_{J\text{max}}$, $I_{\text{AS}}=27\text{A}$, $V_{\text{DD}}=48\text{V}$, $R_{\text{G}}=50\Omega$, Starting $T_J=25^\circ\text{C}$.

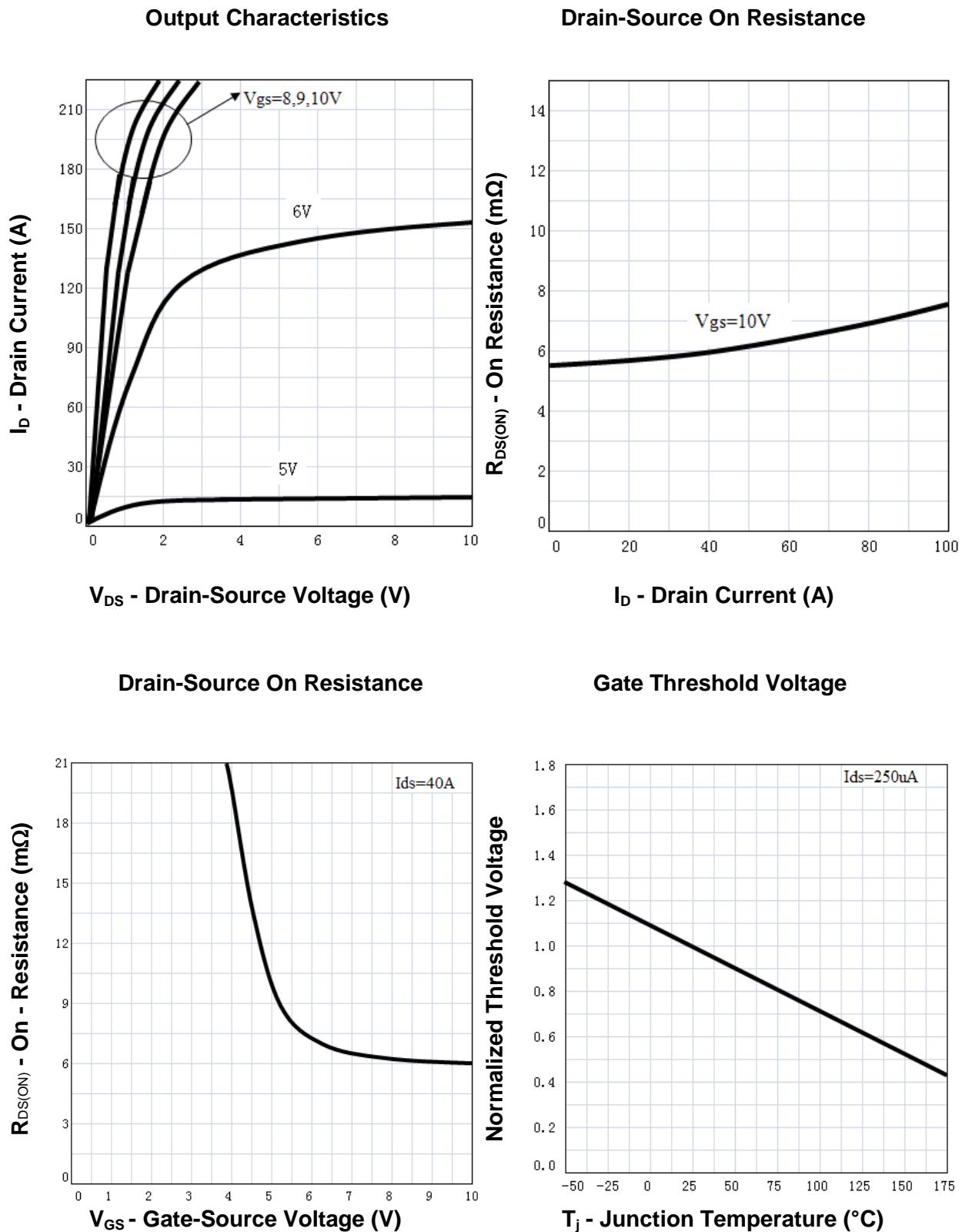
④Pulse test ; Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

⑤Guaranteed by design, not subject to production testing.

Typical Characteristics

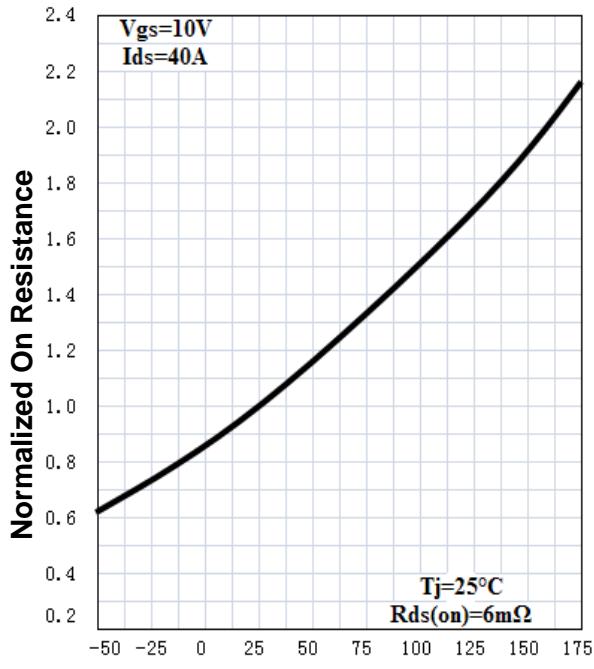


Typical Characteristics

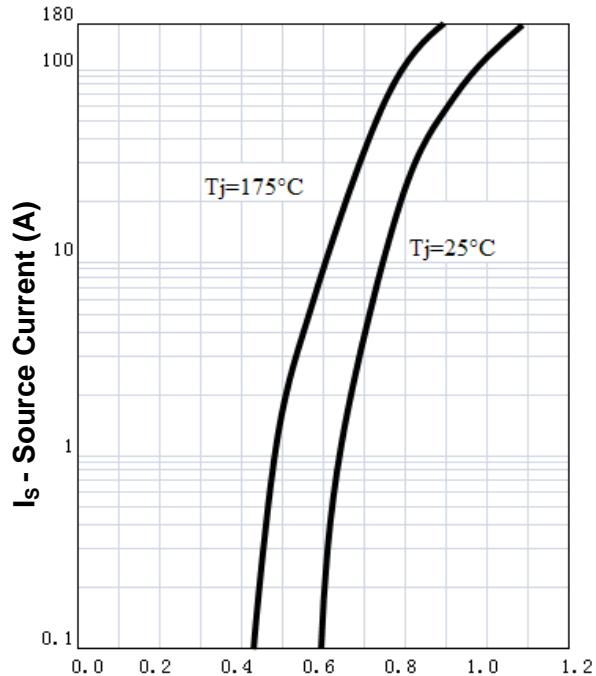


Typical Characteristics

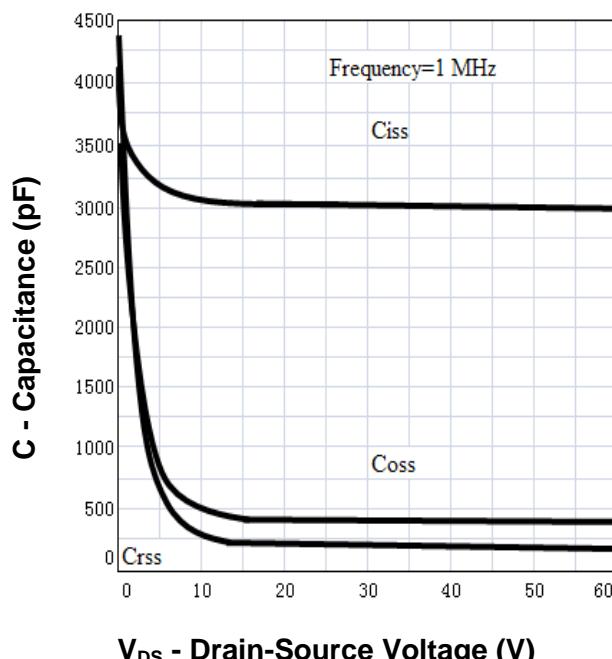
Drain-Source On Resistance



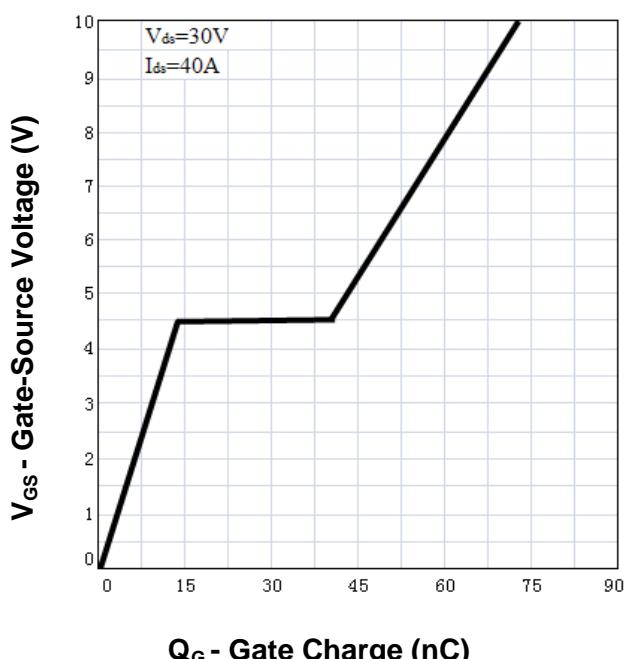
Source-Drain Diode Forward



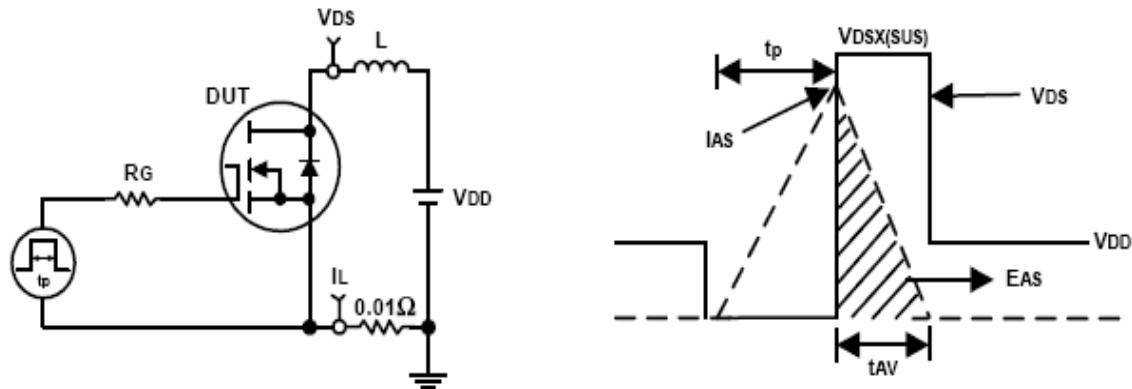
Capacitance



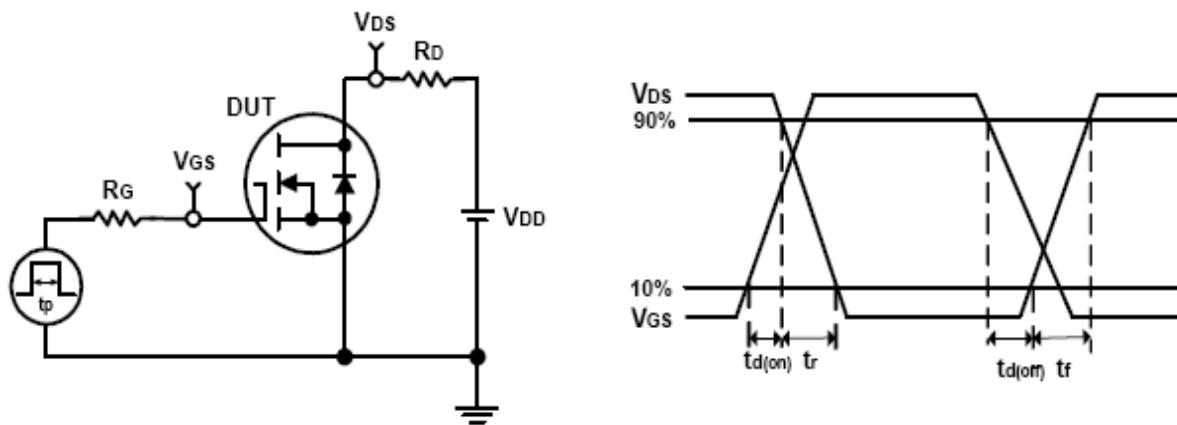
Gate Charge



Avalanche Test Circuit and Waveforms



Switching Time Test Circuit and Waveforms

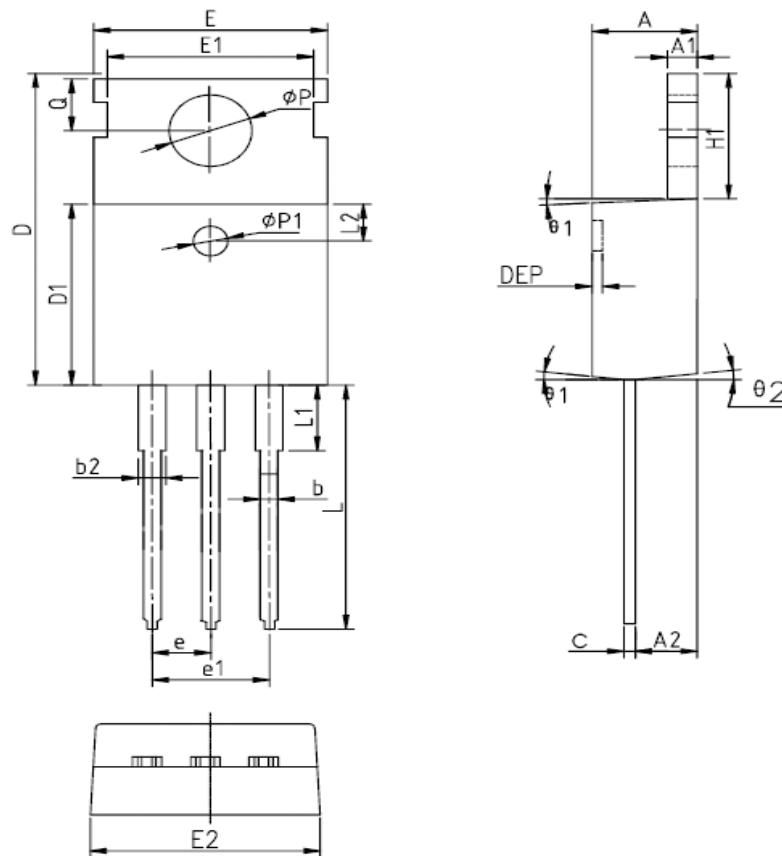


Ordering and Marking Information

Device	Marking	Package	Packaging	Quantity	Reel Size	Tape width
IRF3205Z		TO-220	Tube	50	-	-

Package Information

TO-220FB-3L



SYMBOL	MM			INCH			SYMBOL	MM			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX		MIN	NOM	MAX	MIN	NOM	MAX
A	4.40	4.57	4.70	0.173	0.180	0.185	Øp1	1.40	1.50	1.60	0.055	0.059	0.063
A1	1.27	1.30	1.33	0.050	0.051	0.052	e	2.54BSC			0.1BSC		
A2	2.35	2.40	2.50	0.093	0.094	0.098	e1	5.08BSC			0.2BSC		
b	0.77	-	0.90	0.030	-	0.035	H1	6.40	6.50	6.60	0.252	0.256	0.260
b2	1.23	-	1.36	0.048	-	0.054	L	12.75	-	13.17	0.502	-	0.519
C	0.48	0.50	0.52	0.019	0.020	0.021	L1	-	-	3.95	-	-	0.156
D	15.40	15.60	15.80	0.606	0.614	0.622	L2	2.50REF.			0.098REF.		
D1	9.00	9.10	9.20	0.354	0.358	0.362	Øp	3.57	3.60	3.63	0.141	0.142	0.143
DEP	0.05	0.10	0.20	0.002	0.004	0.008	Q	2.73	2.80	2.87	0.107	0.110	0.113
E	9.70	9.90	10.10	0.382	0.389	0.398	θ1	5°	7°	9°	5°	7°	9°
E1	-	8.70	-	-	0.343	-	θ2	1°	3°	5°	1°	3°	5°
E2	9.80	10.00	10.20	0.386	0.394	0.401							

ALL DIMENSIONS REFER TO JEDEC STANDARD
DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS